

HCT-IA0905-1302-02 FCC ID: US7-A200 May 20, 2009 Report No.: Date of Issue:

APPENDIX A. HAC TEST PLOTS



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /1013 Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: CDMA 835MHz FCC; Frequency: 824,7 MHz; Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1000 kg/m³ Phantom section: E Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

- DASY4 Configuration:
 Probe: ER3DV6 SN2417; ConvF(1, 1, 1); Calibrated: 2008-08-22
 Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn479; Calibrated: 2009-03-13Phantom: HAC Test Arch; Type: SD HAC P01 BA

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 37.8 V/m Probe Modulation Factor = 0.961

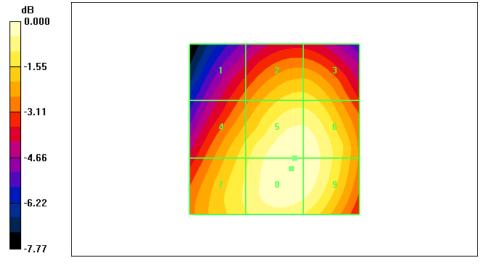
Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 45.8 V/m; Power Drift = 0.214 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
27.5 M4	32.7 M4	32.7 M4
Grid 4	Grid 5	Grid 6
32.9 M4	37.7 M4	37.5 M4
Grid 7	Grid 8	Grid 9
34.0 M4	37.8 M4	37.6 M4

Cursor: Total = 37.8 V/m E Category: M4

Location: -5, 11.5, 369.9 mm



0 dB = 37.8V/m



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /384 Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: CDMA 835MHz FCC; Frequency: 836,52 MHz;Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1000 kg/m³ Phantom section: E Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

DASY4 Configuration:

- Probe: ER3DV6 SN2417; ConvF(1, 1, 1); Calibrated: 2008-08-22 Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn479; Calibrated: 2009-03-13Phantom: HAC Test Arch; Type: SD HAC P01 BA

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 42.8 V/m Probe Modulation Factor = 0.961

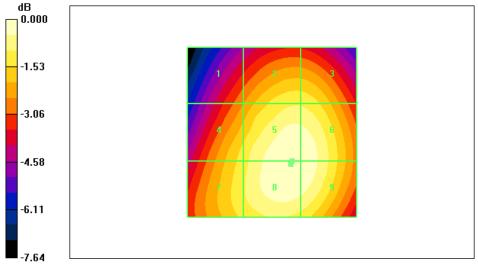
Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 55.5 V/m; Power Drift = -0.176 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
31.9 M4	37.8 M4	37.8 M4
Grid 4	Grid 5	Grid 6
37.1 M4	42.8 M4	42.5 M4
Grid 7	Grid 8	Grid 9
37.8 M4	42.8 M4	42.5 M4

Cursor: Total = 42.8 V/m E Category: M4

Location: -5.5, 9.5, 369.9 mm



0 dB = 42.8V/m



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /777 Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: CDMA 835MHz FCC; Frequency: 848,31 MHz;Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1000 kg/m³ Phantom section: E Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

DASY4 Configuration:

- Probe: ER3DV6 SN2417; ConvF(1, 1, 1); Calibrated: 2008-08-22 Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn479; Calibrated: 2009-03-13 Phantom: HAC Test Arch; Type: SD HAC P01 BA

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 45.7 V/m

Probe Modulation Factor = 0.961

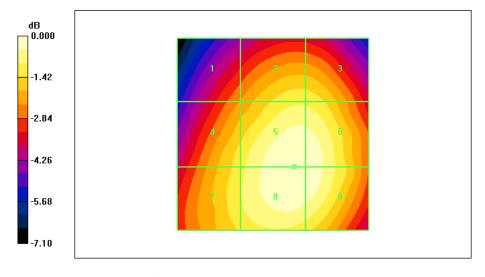
Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 57.9 V/m; Power Drift = -0.099 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
35.0 M4	40.6 M4	40.5 M4
Grid 4	Grid 5	Grid 6
40.2 M4	45.7 M4	45.5 M4
Grid 7	Grid 8	Grid 9
40.8 M4	45.7 M4	45.5 M4

Cursor: Total = 45.7 V/m

E Category: M4 Location: -5.5, 8.5, 369.9 mm



0 dB = 45.7 V/m



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /25

May 15, 2009 Test Date

DUT: A200; Type: folder; Serial: #1

Communication System: PCS 1900MHz FCC; Frequency: 1851,25 MHz;Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1000 kg/m³ Phantom section: E Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

- DASY4 Configuration:
 Probe: ER3DV6 SN2417; ConvF(1, 1, 1); Calibrated: 2008-08-22
 Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn479; Calibrated: 2009-03-13Phantom: HAC Test Arch; Type: SD HAC P01 BA

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 29.5 V/m Probe Modulation Factor = 0.974

Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 18.1 V/m; Power Drift = -0.122 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

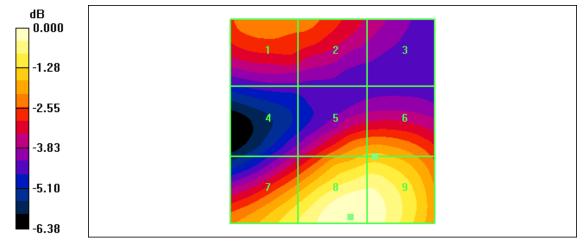
Peak E-field in V/m

Grid 1	Grid 2	Grid 3
23.0 M4	22.5 M4	19.8 M4
Grid 4	Grid 5	Grid 6
19.5 M4	24.6 M4	24.7 M4
Grid 7	Grid 8	Grid 9
26.9 M4	29.5 M4	29.2 M4

Cursor:

Total = 29.5 V/m E Category: M4

Location: -4.5, 23.5, 369.9 mm



0 dB = 29.5 V/m



FCC ID: Report No.: HCT-IA0905-1302-02 US7-A200 **Date of Issue:** May 20, 2009

Test Laboratory: HCT CO., LTD. 21.4 °C /600 Ambient Temperature / Channel Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: PCS 1900MHz FCC; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1000 kg/m³ Phantom section: E Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD,

V1.8 Build 176

DASY4 Configuration:
- Probe: ER3DV6 - SN2417; ConvF(1, 1, 1); Calibrated: 2008-08-22
- Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn479; Calibrated: 2009-03-13 - Phantom: HAC Test Arch; Type: SD HAC P01 BA

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 31.2~V/m

Probe Modulation Factor = 0.974

Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 16.8 V/m; Power Drift = -0.022 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

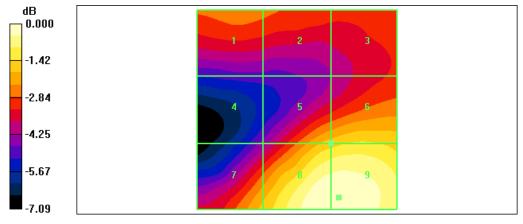
Peak E-field in V/m

Grid 1	Grid 2	Grid 3
23.2 M4	22.9 M4	22.0 M4
Grid 4	Grid 5	Grid 6
18.7 M4	25.9 M4	26.8 M4
Grid 7	Grid 8	Grid 9
25.6 M4	31.1 M4	31.2 M4

Cursor:

Total = 31.2 V/m

E Category: M4 Location: -10.5, 22, 369.9 mm



TEL: +82 31 639 8565

0 dB = 31.2V/m

FAX: +82 31 639 8525 www.hct.co.kr



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /1175 Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: PCS 1900MHz FCC; Frequency: 1908,75 MHz;Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1000 kg/m³ Phantom section: E Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

DASY4 Configuration:

- Probe: ER3DV6 SN2417; ConvF(1, 1, 1); Calibrated: 2008-08-22
- Probe: ERSD vo SN2417, Convr(1, 1, 1), Cambrat Sensor-Surface: (Fix Surface) Electronics: DAE3 Sn479; Calibrated: 2009-03-13 Phantom: HAC Test Arch; Type: SD HAC P01 BA

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

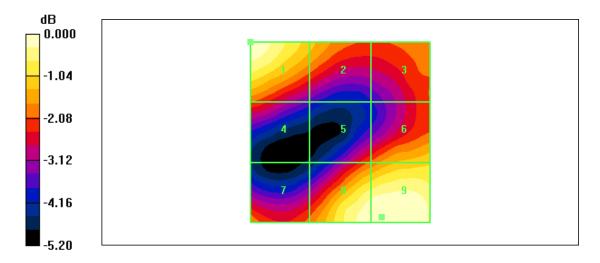
Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 21.9 V/m

Probe Modulation Factor = 0.974 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 11.5 V/m; Power Drift = -0.055 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
21.8 M4	19.0 M4	18.0 M4
Grid 4	Grid 5	Grid 6
17.3 M4	17.4 M4	19.3 M4
Grid 7	Grid 8	Grid 9
18.0 M4	21.7 M4	21.9 M4

Cursor: Total = 21.9 V/m E Category: M4 Location: -11.5, 23.5, 369.9 mm



0 dB = 21.9V/m



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /25 Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: AWS 1700 MHz FCC; Frequency: 1711.25 MHz; Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1000 kg/m³ Phantom section: E Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

DASY4 Configuration:

- Probe: ER3DV6 SN2417; ConvF(1, 1, 1); Calibrated: 2008-08-22
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn479; Calibrated: 2009-03-13 Phantom: HAC Test Arch; Type: SD HAC P01 BA

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 24.2 V/m

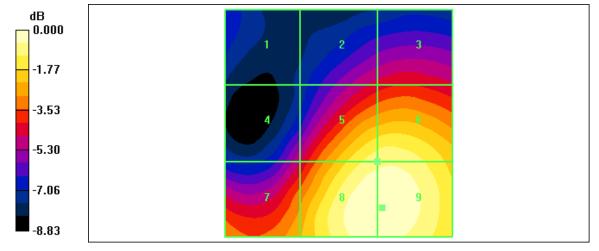
Probe Modulation Factor = 0.974 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 20.0 V/m; Power Drift = 0.064 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
11.4 M4	14.5 M4	15.1 M4
Grid 4	Grid 5	Grid 6
14.1 M4	22.1 M4	22.4 M4
Grid 7	Grid 8	Grid 9
18.4 M4	24.2 M4	24.2 M4

Cursor: Total = 24.2 V/m

E Category: M4 Location: -9.5, 18.5, 369.9 mm



0 dB = 24.2V/m



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /450 Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: AWS 1700 MHz FCC; Frequency: 1732.5 MHz;Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1000 kg/m³ Phantom section: E Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

DASY4 Configuration:

- Probe: ER3DV6 SN2417; ConvF(1, 1, 1); Calibrated: 2008-08-22
- Sensor-Surface: (Fix Surface)
 Electronics: DAE3 Sn479; Calibrated: 2009-03-13
 Phantom: HAC Test Arch; Type: SD HAC P01 BA

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

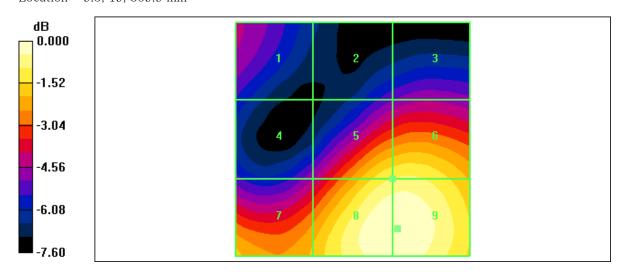
Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 22.6 V/m

Probe Modulation Factor = 0.974 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 17.0 V/m; Power Drift = -0.069 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
13.6 M4	12.6 M4	13.3 M4
Grid 4	Grid 5	Grid 6
13.4 M4	20.1 M4	20.4 M4
Grid 7	Grid 8	Grid 9
18.3 M4	22.5 M4	22.6 M4

Cursor: Total = 22.6 V/m E Category: M4 Location: -9.5, 19, 369.9 mm



0 dB = 22.6V/m



Test Laboratory: HCT CO., LTD. 21.4 °C /875 Ambient Temperature / Channel Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: AWS 1700 MHz FCC; Frequency: 1753.75 MHz;Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1000 kg/m³ Phantom section: E Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

- DASY4 Configuration:
 Probe: ER3DV6 SN2417; ConvF(1, 1, 1); Calibrated: 2008-08-22
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn479; Calibrated: 2009-03-13 Phantom: HAC Test Arch; Type: SD HAC P01 BA

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 25.0 V/m

Probe Modulation Factor = 0.974Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 19.3 V/m; Power Drift = 0.111 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

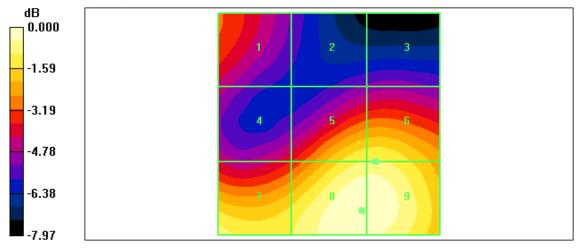
Peak E-field in V/m

Grid 1	Grid 2	Grid 3
17.5 M4	13.8 M4	14.1 M4
Grid 4	Grid 5	Grid 6
16.4 M4	22.3 M4	22.4 M4
Grid 7	Grid 8	Grid 9
22.9 M4	25.0 M4	24.9 M4

Cursor:

Total = 25.0 V/m

E Category: M4 Location: -7.5, 19.5, 369.9 mm



0 dB = 25.0V/m

FAX: +82 31 639 8525 www.hct.co.kr

TEL: +82 31 639 8565



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /1013 Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: CDMA 835MHz FCC; Frequency: 824.7 MHz; Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1 kg/m³ Phantom section: H Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD,

V1.8 Build 176

DASY4 Configuration:

- Probe: H3DV6 - SN6251; ; Calibrated: 2008-08-22

- Probe. H3DV6 - SN0251, , Calibrated. 2006 06 2 - Sensor-Surface: (Fix Surface) - Electronics: DAE3 Sn479; Calibrated: 2009-03-13 - Phantom: HAC Test Arch; Type: SD HAC P01 BA

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.076 A/m Probe Modulation Factor = 0.852

Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.061 A/m; Power Drift = -0.200 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

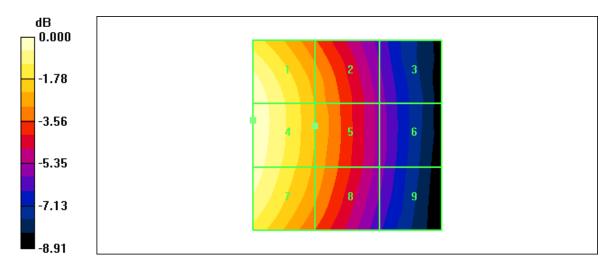
Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.075 M4	0.057 M4	0.040 M4
Grid 4	Grid 5	Grid 6
0.076 M4	0.058 M4	0.040 M4
Grid 7	Grid 8	Grid 9
0.074 M4	0.057 M4	0.040 M4

Cursor:

Total = 0.076 A/m

H Category: M4 Location: 25, -4, 369.4 mm



0 dB = 0.076A/m



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /384 Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: CDMA 835MHz FCC; Frequency: 836.52 MHz; Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1 kg/m³ Phantom section: H Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

DASY4 Configuration:

- Probe: H3DV6 SN6251; ; Calibrated: 2008-08-22

- Probe. H3DV6 SN0251, , Calibrated. 2006 06 2 Sensor-Surface: (Fix Surface) Electronics: DAE3 Sn479; Calibrated: 2009-03-13 Phantom: HAC Test Arch; Type: SD HAC P01 BA

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.086 A/m Probe Modulation Factor = 0.852

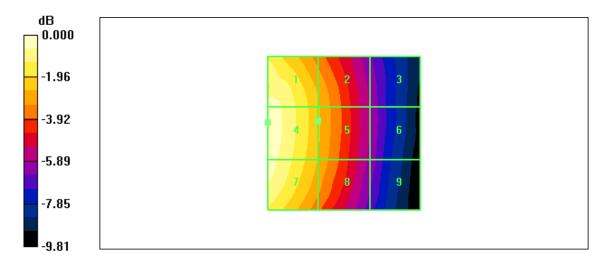
Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.066 A/m; Power Drift = -0.020 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.085 M4	0.064 M4	0.043 M4
Grid 4	Grid 5	Grid 6
0.086 M4	0.065 M4	0.044 M4
Grid 7	Grid 8	Grid 9
0.083 M4	0.063 M4	0.043 M4

Cursor: Total = 0.086 A/m

H Category: M4 Location: 25, -3.5, 369.4 mm



0 dB = 0.086A/m



FCC ID: Report No.: HCT-IA0905-1302-02 US7-A200 **Date of Issue:** May 20, 2009

Test Laboratory: HCT CO., LTD. 21.4 °C /777 Ambient Temperature / Channel Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: CDMA 835MHz FCC; Frequency: 848.31 MHz;Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1 kg/m³ Phantom section: H Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

DASY4 Configuration:
- Probe: H3DV6 - SN6251; ; Calibrated: 2008-08-22
- Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn479; Calibrated: 2009-03-13 - Phantom: HAC Test Arch; Type: SD HAC P01 BA

H Scan – H3DV6 – 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.084 A/m

Probe Modulation Factor = 0.852

Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.063 A/m; Power Drift = -0.011 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

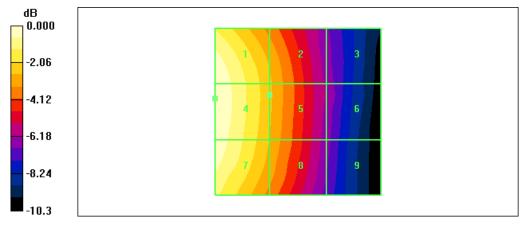
Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.084 M4	0.062 M4	0.041 M4
Grid 4	Grid 5	Grid 6
0.084 M4	0.062 M4	0.041 M4
Grid 7	Grid 8	Grid 9
0.082 M4	0.061 M4	0.040 M4

Cursor:

Total = 0.084 A/m

H Category: M4 Location: 25, -4, 369.4 mm



0 dB = 0.084A/m



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /25 Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: PCS 1900MHz FCC; Frequency: 1851.25 MHz;Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1 kg/m³ Phantom section: H Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD,

V1.8 Build 176

DASY4 Configuration:

- Probe: H3DV6 - SN6251; ; Calibrated: 2008-08-22

- Probe: H3D vo - SN0231, Cambrated: 2000 00 2. - Sensor-Surface: (Fix Surface) - Electronics: DAE3 Sn479; Calibrated: 2009-03-13 - Phantom: HAC Test Arch; Type: SD HAC P01 BA

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.065 A/m

Probe Modulation Factor = 0.750

Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.051 A/m; Power Drift = -0.040 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

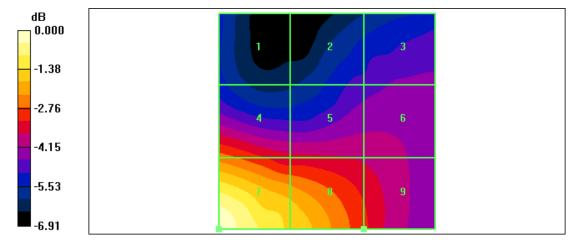
Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.035 M4	0.037 M4	0.039 M4
Grid 4	Grid 5	Grid 6
0.049 M4	0.043 M4	0.042 M4
Grid 7	Grid 8	Grid 9
0.065 M4	0.055 M4	0.046 M4

Cursor:

Total = 0.065 A/m

H Category: M4 Location: 25, 25, 369.4 mm



0 dB = 0.065A/m



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /600 Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: PCS 1900MHz FCC; Frequency: 1880 MHz; Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1 kg/m³ Phantom section: H Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

DASY4 Configuration:

- Probe: H3DV6 - SN6251; ; Calibrated: 2008-08-22

- Probe: H3D vo - SN0231, Cambrated: 2000 vo 2.
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn479; Calibrated: 2009-03-13
- Phantom: HAC Test Arch; Type: SD HAC P01 BA

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.068 A/m

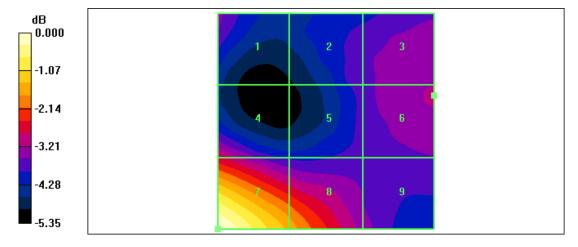
Probe Modulation Factor = 0.750 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.056 A/m; Power Drift = -0.132 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.046 M4	0.045 M4	0.047 M4
Grid 4	Grid 5	Grid 6
0.050 M4	0.044 M4	0.047 M4
Grid 7	Grid 8	Grid 9
0.068 M4	0.057 M4	0.046 M4

Cursor: Total = 0.068 A/m H Category: M4 Location: 25, 25, 369.4 mm



0 dB = 0.068A/m



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /1175 Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: PCS 1900MHz FCC; Frequency: 1908.75 MHz;Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1 kg/m³ Phantom section: H Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD,

V1.8 Build 176

DASY4 Configuration:

- Probe: H3DV6 - SN6251; ; Calibrated: 2008-08-22

- Probe: H3D vo - SN0231, Cambrated: 2000 vo 2.
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn479; Calibrated: 2009-03-13
- Phantom: HAC Test Arch; Type: SD HAC P01 BA

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.055 A/m

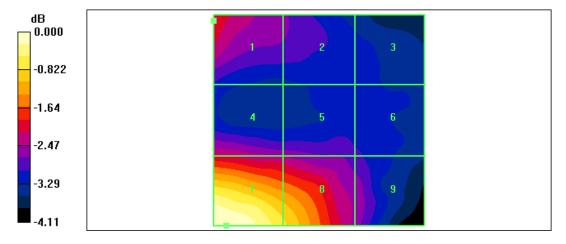
Probe Modulation Factor = 0.750 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.050 A/m; Power Drift = 0.140 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.044 M4	0.040 M4	0.039 M4
Grid 4	Grid 5	Grid 6
0.043 M4	0.041 M4	0.039 M4
Grid 7	Grid 8	Grid 9
0.055 M4	0.050 M4	0.041 M4

Cursor: Total = 0.055 A/m H Category: M4 Location: 22, 25, 369.4 mm



0 dB = 0.055A/m



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /25 Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: AWS 1700 MHz FCC; Frequency: 1711.25 MHz; Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1 kg/m³ Phantom section: H Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

DASY4 Configuration:

- Probe: H3DV6 SN6251; ; Calibrated: 2008-08-22
- Probe: H3D vo SN0231, Cambrated: 2000 00 2. Sensor-Surface: (Fix Surface) Electronics: DAE3 Sn479; Calibrated: 2009-03-13 Phantom: HAC Test Arch; Type: SD HAC P01 BA

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

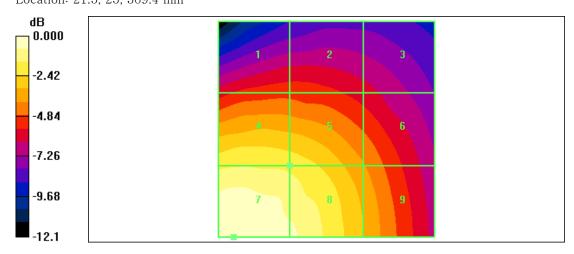
Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.061 A/m

Probe Modulation Factor = 0.750 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.055 A/m; Power Drift = 0.062 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.034 M4	0.034 M4	0.030 M4
Grid 4	Grid 5	Grid 6
0.051 M4	0.049 M4	0.039 M4
Grid 7	Grid 8	Grid 9
0.061 M4	0.057 M4	0.042 M4

Cursor: Total = 0.061 A/m H Category: M4 Location: 21.5, 25, 369.4 mm



0 dB = 0.061A/m



Test Laboratory: HCT CO., LTD. Ambient Temperature / Channel 21.4 °C /450 Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: AWS 1700 MHz FCC; Frequency: 1732.5 MHz;Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1 kg/m³ Phantom section: H Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

DASY4 Configuration:

- Probe: H3DV6 SN6251; ; Calibrated: 2008-08-22
- Probe: H3D vo SN0231, Cambrated: 2000 vo 2.
 Sensor-Surface: (Fix Surface)
 Electronics: DAE3 Sn479; Calibrated: 2009-03-13
 Phantom: HAC Test Arch; Type: SD HAC P01 BA

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.058 A/m

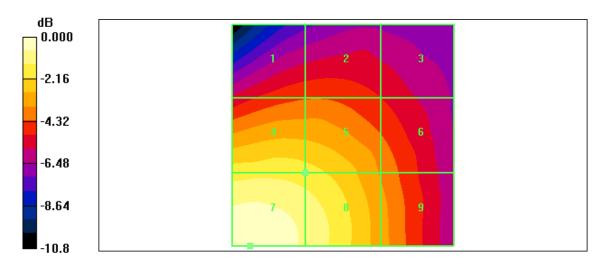
Probe Modulation Factor = 0.750 Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.056 A/m; Power Drift = -0.084 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.035 M4	0.035 M4	0.033 M4
Grid 4	Grid 5	Grid 6
0.048 M4	0.047 M4	0.038 M4
Grid 7	Grid 8	Grid 9
0.058 M4	0.053 M4	0.040 M4

Cursor: Total = 0.058 A/m H Category: M4 Location: 21, 25, 369.4 mm



0 dB = 0.058A/m



FCC ID: Report No.: HCT-IA0905-1302-02 US7-A200 **Date of Issue:** May 20, 2009

HCT CO., LTD. Test Laboratory: 21.4 °C /875 Ambient Temperature / Channel Test Date May 15, 2009

DUT: A200; Type: folder; Serial: #1

Communication System: AWS 1700 MHz FCC; Frequency: 1753.75 MHz; Duty Cycle: 1:1 Medium parameters used: σ = 0 mho/m, ϵ_r = 1; ρ = 1 kg/m³ Phantom section: H Device Section; Measurement SW: DASY4, V4.7 Build 71; Postprocessing SW: SEMCAD, V1.8 Build 176

- DASY4 Configuration:
 Probe: H3DV6 SN6251; ; Calibrated: 2008-08-22
 Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn479; Calibrated: 2009-03-13 Phantom: HAC Test Arch; Type: SD HAC P01 BA

H Scan – H3DV6 – 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.060 A/m

Probe Modulation Factor = 0.750

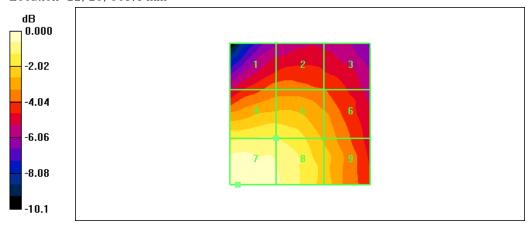
Device Reference Point: 0.000, 0.000, 353.7 mm Reference Value = 0.063 A/m; Power Drift = 0.070 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.039 M4	0.040 M4	0.038 M4
Grid 4	Grid 5	Grid 6
0.052 M4	0.051 M4	0.044 M4
Grid 7	Grid 8	Grid 9
0.060 M4	0.056 M4	0.046 M4

Cursor:

Total = 0.060 A/mH Category: M4 Location: 22, 25, 369.4 mm



0 dB = 0.060A/m